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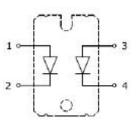
Parallel Fast Recovery, 2X75A, 600V Diodes In Isolated SOT227 Package

APPLICATIONS

- > Switch mode power supplies (SMPS) rectifiers
- Resonant applications
- Industrial drives

FEATURES

- ➢ Fast recovery
- Soft switching
- Low reverse recovery charge
- Low forward voltage drop
- Low leakage current
- Pb-free finished; RoHS compliant





Maximum Ratings (per Diode)

Parameter	Symbol	Value	Units
Repetitive peak reverse voltage	V _{RRM}	600	V
Continuous forward current Tc= 25°C Tc= 77°C	lF	100 75	
Surge non-repetitive forward current T _C = 25°C, t_p = 10 ms, sine halfwave	IFSM	220	A
Maximum repetitive forward current T _C = 25°C, t _p limited by T_{jmax} , D = 0.5	I _{FRM}	225	
Soldering temperature Wave soldering, 1.6 mm (0.063 in.) from case for 10s	Ts	260	°C
Operating junction and storage temperature	Tj, Tstg	-55 +175	°C

Thermal and Isolation Characteristics

Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case, per Diode	RthJC	0.65	
Thermal resistance, junction to ambient, leaded	R _{thJA}	40	K/W
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	Viso	3000	V

Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Parameter	Symbol	Value			11
		Min.	Тур.	Max.	Unit
Static Characteristics					
Reverse leakage current VR = 600V, Tj = 25°C VR = 600V, Tj = 175°C	I _R	-	-	40 1000	μA
Forward voltage drop IF = 75A, Tj = 25°C IF = 75A, Tj = 175°C	VF	-	1.65 1.65	2.0	V

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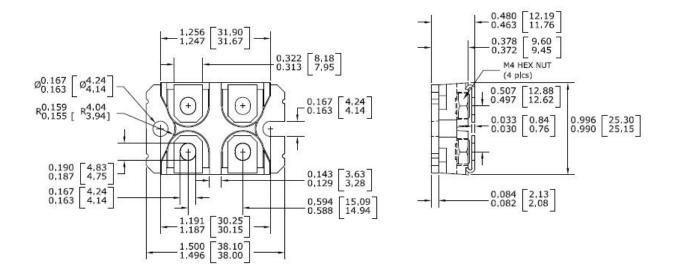
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Parameter	Symphol	Value			11 *4
	Symbol	Min.	Тур.	Max.	Unit
Dynamic Characteristics					
Reverse recovery time $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 25^{\circ}C$ $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 125^{\circ}C$	trr	-	264 548	-	ns
Peak reverse current V _R = 300V, I _F = 75A, di _F /dt = 200A/µs, T _J = 25°C V _R = 300V, I _F = 75A, di _F /dt = 200A/µs, T _J = 125°C	Irm	-	8.3 12.9		А
Reverse recovery charge $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 25 \circ C$ $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 125 \circ C$	Qrr	-	908 2941	-	nC

Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Package Outline Drawing



Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**

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